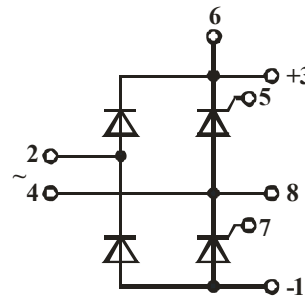
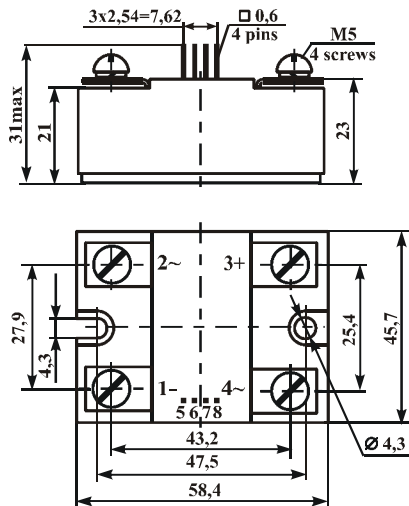


SINGLE-PHASE THYRISTOR-DIODE BRIDGE MODULE M21-63-12

DATASHEET IN BRIEF

A single-phase thyristor-diode bridge module with control of two thyristors, connected to “positive” and “negative” outputs, is intended for rectifying (converting of AC into pulsating direct voltage).

OVERALL DRAWING AND ELECTRIC CIRCUIT



BASIC CHARACTERISTICS

T = 25 °C

Product name	Pulse voltage: in thyristor on-state/ diode direct, U_{TM}/U_{FM}		Current in thyristor off-state /rectifier reverse current, I_D/I_R , mA		Thyristor hold-on current, I_H , mA	Thyristor turn-on current, I_s , mA	Thyristor gate trigger DC voltage, U_{GT} , V	Thyristor gate trigger DC, I_{GT} , mA	Electric isolation strength at DC between radiator and outputs, U_{ISOL} , V		Thyristor non-trigger DC voltage, U_{GD} , V $T_j = 125\text{ °C}$	Thermal junction-radiator resistance $R_{th(j-c)}$, °C/W	
	V	I_O , A ampl. value	max	U_O , V	max	max	max	max	min	t , minute		thyristor	diode
M21-63-12	1.65	$\frac{\pi}{2} \cdot I_O$ 10 ms, 50 Hz, sinus	1.5	± 1200	200	400	3.0	200	4000	1	0.25	1.0	1.3

MAXIMUM ALLOWABLE OPERATING MODES

Product name	Pulse non-repetitive voltage: in thyristor off-state/ diode reverse, U_{DSM}/U_{RSM} , V	Pulse repetitive voltage: in thyristor off-state / diode reverse, U_{DRM}/U_{RRM} , V	Average rectified current, I_O , A $T_r=75\text{ °C}$	Linear voltage (rms), U_{lin} , V	Non-repetitive surge DC, $I_{TSM} I_{FSM}$, A	Maximum switching frequency, f_{com} , kHz	Critical rate of rise of reverse voltage, $(du_R/dt)_{cr}$, V/ μ s	DC critical rate of rise, $(di_T/dt)_{cr}$, A/ μ s	Junction temperature T_{VJ} *, °C	
									min	max
M21-63-12	max	max	max	max	max	3	max	max	min	max
	± 1300	± 1200	63	840	300	10	1000	150	-40	+125

* the modules are designed for operating in the equipment with using of coolers that support transition temperature in the prescribed ranges

Precious metals are not contained.